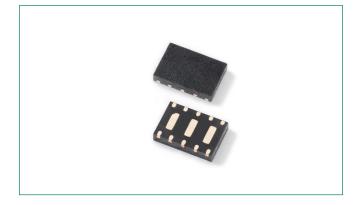
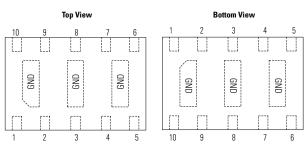


SP3374NUTG 3.3V 40A Diode Array



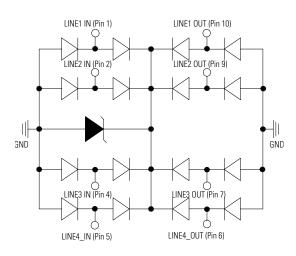


Pinout



NOTE: PIN3, PIN8 are same potential with GND

Functional Block Diagram



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Description

The SP3374NUTG is a low-capacitance, TVS Diode Array designed to provide protection against ESD (electrostatic discharge), CDE (cable discharge events), EFT (electrical fast transients), and lightning induced surges for high-speed, differential data lines. It's packaged in a μ DFN package (3.0 x 2.0mm) and each device can protect up 4 channels or 2 differential pairs, up to 40A (IEC 61000-4-5 2nd edition,) and up to 30kV ESD (IEC 61000-4-2). The "flow-through" design minimizes signal distortion, reduces voltage overshoot, and provides a simplified PCB design.

The SP3374NUTG with its low capacitance and low clamping voltage makes it ideal for high-speed data interfaces such as 1GbE applications found in notebooks, switches, etc.

Features

- ESD, IEC 61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC 61000-4-4, 40A (5/50ns)
- Lightning, 40A (8/20µs as defined in IEC 61000-4-5 2nd Edition)
- Low capacitance of 3.5pF@0V (TYP) per I/O
- Low leakage current of 0.1µA (TYP) at 3.3V
- µDFN-10 package is optimized for high-speed data line routing
- Provides protection for two differential data pairs (4 channels) up to 40A
- Low operating and clamping voltage
- AEC-Q101 qualified

LVDS Interfaces

• Smart TV

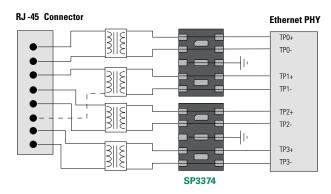
Integrated Magnetics

• Halogen free, Lead free and RoHS compliant

Applications

- •10/100/1000 Ethernet
- WAN/LAN Equipment
- Desktops, Servers and Notebooks

Application Example



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Absolute Maximum Ratings

Symbol	Parameter	Value	Units
l _{pp}	Peak Current (t _p =8/20µs)	40	A
P _{Pk}	Peak Pulse Power ($t_p=8/20\mu s$)	1000	W
T _{op}	Operating Temperature	-40 to 125	°C
T _{STOR}	Storage Temperature	-55 to 150	C

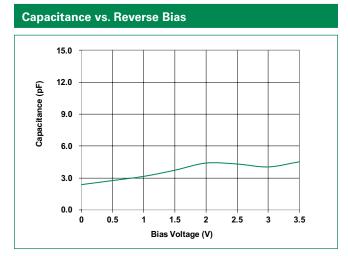
CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Electrical Characteristics (T_{OP}=25°C) Parameter Symbol **Test Conditions** Min Тур Max Units Reverse Standoff Voltage $I_{_{\rm B}} \le 1\mu A$ 3.3 V V_{RWM} Reverse Leakage Current $V_{_{\rm RWM}}=3.3V,T=25^{\circ}C$ 0.1 0.5 μA I_{R} Snap Back Voltage $V_{\rm SB}$ $I_{SB} = 50 \text{mA}$ 2.8 V $I_{pp} = 1A$, $t_p = 8/20 \mu s$ Any I/O to Ground 5.5 $I_{pp} = 10A$, $t_p = 8/20\mu s$ Any I/O to Ground 10.5 Clamp Voltage V_c $I_{pp} = 25A, t_p = 8/20 \mu s$ Any I/O to Ground V 18.0 $I_{pp} = 40A$, $t_p = 8/20\mu s$ Line-to-Line¹, two I/O Pins 25.0 connected together on each line Dynamic Resistance² TLP, t_=100ns, Any I/O to Ground 0.15 Ω $\mathsf{R}_{_{DYN}}$ IEC 61000-4-2 (Contact) ±30 kV ESD Withstand Voltage V_{ESD} IEC 61000-4-2 (Air) ±30 kV Between I/O Pins and Ground pF 5.0 $C_{\rm I/O \ to \ GND}$ 3.5 $V_{p} = 0V, f = 1MHz$ Diode Capacitance Between I/O Pins C_{I/O to I/O} 1.7 рF $V_{R} = 0V$, f = 1MHz

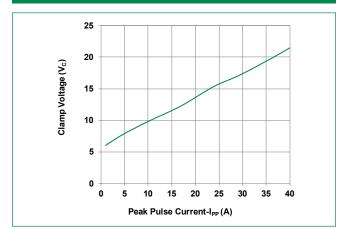
Notes:

1. Rating with 2 pins connected together per sugguested diagram (For example, pin1 is connected to pin 10, pin 2 is connected to Pin 9, Pin 4 is connected to pin 7 and pin 5 is connected to pin 6)
2. Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window t1=70ns to t2=90ns



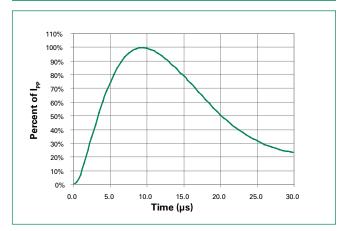


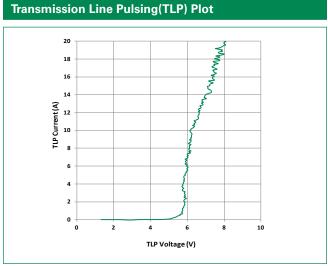
Clamping Voltage vs. I_{PP} (Line-to-Line)



Clamping Voltage vs. $I_{\mu\nu}$ (I/O to GND) 15 12 Clamp Voltage (V_c) 9 6 3 0 15 20 25 0 5 10 Peak Pulse Current-IPP (A)

8/20µS Pulse Waveform

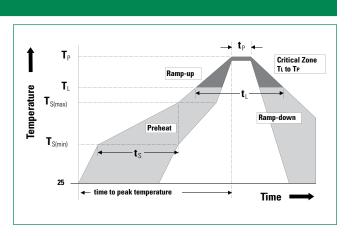






Soldering Parameters

Reflow Condition		Pb – Free assembly	
Pre Heat	- Temperature Min (T _{s(min)})	150°C	
	- Temperature Max (T _{s(max)})	200°C	
	- Time (min to max) (t _s)	60 - 180 secs	
Average ramp up rate (Liquidus) Temp (T_{L}) to peak		3°C/second max	
T _{s(max)} to T _L - Ramp-up Rate		3°C/second max	
Reflow	- Temperature (T _L) (Liquidus)	217°C	
	- Temperature (t _L)	60 - 150 seconds	
Peak Temperature (T _P)		260+0/-5 °C	
Time within 5°C of actual peak Temperature (t _p)		20 – 40 seconds	
Ramp-down Rate		6°C/second max	
Time 25°C to peak Temperature (T _p)		8 minutes Max.	
Do not exceed		260°C	



Ordering Information

Part Number	Package	Min. Order Qty.
SP3374NUTG	µDFN-10 (3.0x2.0mm)	3000

Product Characteristics

Lead Plating	Pre-Plated Frame	
Lead Material	Copper Alloy	
Substrate material	Silicon	
Body Material	Molded Compound	
Flammability	UL Recognized compound meeting flammability rating V-0	

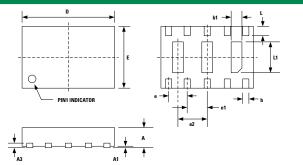
Part Numbering System

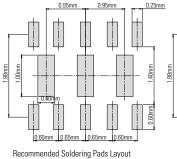
 Part Marking System

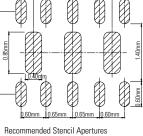




Package Dimensions - µDFN-10 (3.0x2.0mm)







Recommended Stencil thickness 5mils

Package	μDFN-10 (3.0x2.0mm)					
JEDEC	MO-229					
Symbol	Millimeters		Inches			
Symbol	Min	Nom	Max	Min	Nom	Max
Α	0.50	0.60	0.65	0.020	0.024	0.026
A1	0.00	0.03	0.05	0.000	0.001	0.002
A3		0.15 Ref		C	0.006 Ref	
b	0.15	0.20	0.25	0.006	0.008	0.010
b1	0.25	0.35	0.45	0.010	0.014	0.018
D	2.90	3.00	3.10	0.114	0.118	0.122
Е	1.90	2.00	2.10	0.075	0.079	0.083
е	0.60 BSC		0.024 BSC			
e1	0.65 BSC		0.026 BSC			
e2	0.95 BSC		0.037			
L	0.25	0.30	0.35	0.010	0.012	0.014
L1	0.95	1.00	1.05	0.037	0.039	0.041

Notes :

),25mm

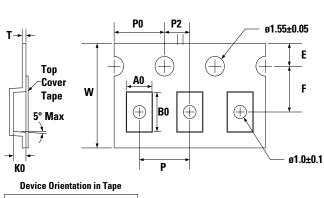
1. All dimensions are in millimeters

Dimensions include solder plating.
Dimensions are exclusive of mold flash & metal burr.

4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.

5. Package surface matte finish VDI 11-13.

Tape & Reel Specification – µDFN-10 (3.0x2.0mm)



Pin1 Location

Package	μDFN-10 (3.0x2.0mm)		
Symbol	Millimeters		
A0	2.30 +/- 0.10		
B0	3.20 +/- 0.10		
E	1.75 +/- 0.10		
F	3.50 +/- 0.05		
КО	1.0 +/- 0.10		
Р	4.00 +/- 0.10		
PO	4.00 +/- 0.10		
P2	2.00 +/- 0.10		
Т	0.3 +/- 0.05		
W	8.00 +0.30/- 0.10		

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